

S-19161A Series

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AUTOMOTIVE, 125°C OPERATION, BATTERY PROTECTION IC FOR 1-CELL PACK

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Features

Rev.1.1_00

This IC is a protection IC for lithium-ion / lithium polymer rechargeable batteries, which includes high-accuracy voltage detection circuits and delay circuits. It is suitable for protecting 1-cell lithium-ion / lithium polymer rechargeable battery packs from overcharge, overdischarge, and overcurrent.

Caution This product can be used in vehicle equipment and in-vehicle equipment. Before using the product for these purposes, it is imperative to contact our sales representatives.

High-accuracy voltage detection circuit 3.500 V to 4.800 V (5 mV step) Overcharge detection voltage Accuracy ±15 mV Overcharge release voltage 3.100 V to 4.800 V*1 Accuracy ±50 mV Overdischarge detection voltage 2.000 V to 3.000 V (10 mV step) Accuracy ±50 mV Overdischarge release voltage 2.000 V to 3.400 V*2 Accuracy ±75 mV Discharge overcurrent 1 detection voltage 5 mV to 100 mV (0.5 mV step) Accuracy ±1.5 mV Discharge overcurrent 2 detection voltage 10 mV to 100 mV (1 mV step) Accuracy ±3 mV Load short-circuiting detection voltage 20 mV to 100 mV (1 mV step) Accuracy ±5 mV 101 mV to 300 mV (1 mV step) Accuracy ±10 mV Charge overcurrent detection voltage -100 mV to -5 mV (0.5 mV step) Accuracy ±1.5 mV Detection delay times are generated only by an internal circuit (external capacitors are unnecessary). Discharge overcurrent control function Release condition of discharge overcurrent status: Load disconnection Release voltage of discharge overcurrent status: Discharge overcurrent release voltage (V_{RIOV}) = $V_{DD} \times 0.8$ (typ.) • 0 V battery charge: Enabled, inhibited • Power-down function: Available, unavailable · High-withstand voltage: VM pin and CO pin: Absolute maximum rating 28 V • Wide operation temperature range: Ta = -40°C to +125°C Low current consumption 2.0 µA typ., 4.0 µA max. (Ta = +25°C) During operation: 50 nA max. (Ta = +25°C) During power-down: During overdischarge: 0.5 µA max. (Ta = +25°C)

- Lead-free (Sn 100%), halogen-free
- AEC-Q100 in process*3
- *1. Overcharge release voltage = Overcharge detection voltage Overcharge hysteresis voltage (Overcharge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.4 V in 50 mV step.)
- *2. Overdischarge release voltage = Overdischarge detection voltage + Overdischarge hysteresis voltage (Overdischarge hysteresis voltage can be selected as 0 V or from a range of 0.1 V to 0.7 V in 100 mV step.)
- *3. Contact our sales representatives for details.

Applications

- Lithium-ion rechargeable battery pack
- Lithium polymer rechargeable battery pack

Package

• SOT-23-6

Block Diagram

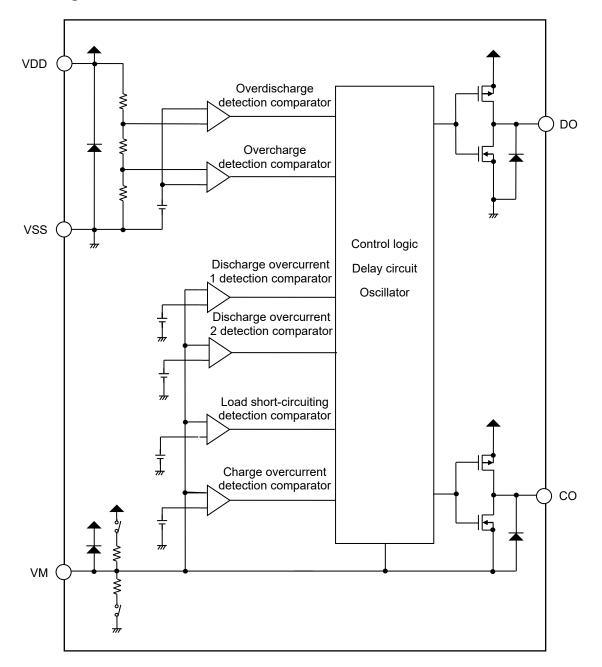


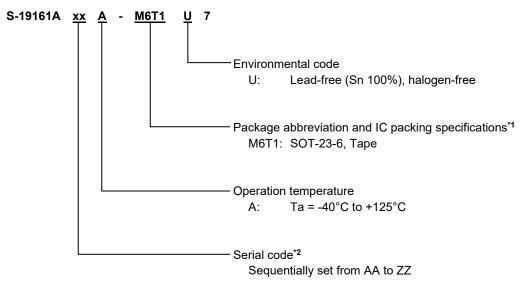
Figure 1

■ AEC-Q100 in Process

Contact our sales representatives for details of AEC-Q100 reliability specification.

Product Name Structure

1. Product name



- *1. Refer to the tape drawing.
- *2. Refer to "3. Product name list".

2. Package

Package Name	Dimension	Таре	Reel
SOT-23-6	MP006-A-P-SD	MP006-A-C-SD	MP006-A-R-SD

3. Product name list

Table 2 (1 / 2)

	Overcharge	Overcharge	Overdischarge	Overdischarge	Discharge	Discharge
Product Name	Detection	Release	Detection	Release	Overcurrent 1	Overcurrent 2
	Voltage	Voltage	Voltage	Voltage	Detection Voltage	Detection Voltage
	[Vcu]	[Vcl]	[Vdl]	[Vdu]	[VDIOV1]	[Vdiov2]
S-19161AACA-M6T1U7	4.280 V	4.080 V	2.800 V	3.000 V	100 mV	-

Table	2	(2 /	2)
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Product Name	Load Short-circuiting Detection Voltage [V _{SHORT}]	Charge Overcurrent Detection Voltage [V _{CIOV}]	Delay Time Combination ^{*1}	0 V Battery Charge*²	Power-down Function ^{*3}
S-19161AACA-M6T1U7	300 mV	-100 mV	(1)	Inhibited	Unavailable

*1. Refer to Table 3 about the details of the delay time combinations.

*2. 0 V battery charge: Enabled, inhibited

***3.** Power-down function: Available, unavailable

Remark Please contact our sales representatives for products other than the above.

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	Table 3								
Delay Time Combination	Overcharge Detection Delay Time [tcu]	Overdischarge Detection Delay Time [t _{DL}]	Discharge Overcurrent 1 Detection Delay Time [t _{DIOV1}]	Discharge Overcurrent 2 Detection Delay Time [t _{DIOV2}]	Load Short- circuiting Detection Delay Time [tsнокт]	Charge Overcurrent Detection Delay Time [tciov]			
(1)	1.0 s	128 ms	8 ms	-	280 µs	8 ms			

Remark The delay times can be changed within the range listed in **Table 4**. For details, please contact our sales representatives.

Delay Time	Symbol		Selection Range				Remark	
Overcharge detection delay time	tcu	256 ms	512 ms	1.0 s	-	-	-	Select a value from the left.
Overdischarge detection delay time	t _{DL}	32 ms	64 ms	128 ms	-	-	-	Select a value from the left.
Discharge overcurrent 1 detection delay time	t _{DIOV1}	8 ms 512 ms	16 ms 1.0 s	32 ms 2.0 s	64 ms 3.0 s	128 ms 3.75 s	256 ms 4.0 s	Select a value from the left.
Discharge overcurrent 2 detection delay time	t _{DIOV2}	4 ms	8 ms	16 ms	32 ms	64 ms	128 ms	Select a value from the left.
Load short-circuiting detection delay time	t SHORT	280 µs	530 µs	-	-	-	-	Select a value from the left.
Charge overcurrent detection delay time	tciov	4 ms	8 ms	16 ms	32 ms	64 ms	128 ms	Select a value from the left.

Pin Configuration

1. SOT-23-6

Top view

6 日	5 日	4 日	
日 1	日 2	日 3	
Fiç	gur	e 2	

	Pin No.	Symbol	Description
	1	DO	Connection pin of discharge control FET gate (CMOS output)
	2	CO	Connection pin of charge control FET gate (CMOS output)
	3	VM	Input pin for external negative voltage
ſ	4	NC ^{*1}	No connection
	5	VDD	Input pin for positive power supply
	6	VSS	Input pin for negative power supply

***1.** The NC pin is electrically open.

The NC pin can be connected to the VDD pin or the VSS pin.

Absolute Maximum Ratings

Table 6

			(Ta = +25°C unless otherv	vise specified)
Item	Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	VDS	VDD	V _{SS} - 0.3 to V _{SS} + 6	V
VM pin input voltage	Vvм	VM	V _{DD} - 28 to V _{DD} + 0.3	V
DO pin output voltage	Vdo	DO	Vss - 0.3 to V _{DD} + 0.3	V
CO pin output voltage	Vco	СО	V _{VM} - 0.3 to V _{DD} + 0.3	V
Operation ambient temperature	T _{opr}	-	-40 to +125	°C
Storage temperature	T _{stg}	-	-55 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Thermal Resistance Value

Table 7

Item	Symbol	Condition		Min.	Тур.	Max.	Unit
Junction-to-ambient thermal resistance*1	θја		Board A	-	159	-	°C/W
			Board B	-	124	-	°C/W
		SOT-23-6	Board C	-	-	-	°C/W
			Board D	-	-	-	°C/W
			Board E	-	-	-	°C/W

***1.** Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "■ **Power Dissipation**" and "Test Board" for details.

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Electrical Characteristics

1. Ta = +25°C

Table 8

			(Ta =	+25°C ι	Inless otherwi	se sp	ecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection Voltage							
Overcharge detection voltage	Vcu	-	V _{CU} - 0.015	Vcu	V _{CU} + 0.015	V	1
Overeberge release veltage	Max.	Vc∟ ≠ Vc∪	V _{CL} - 0.050	Vcl	V _{CL} + 0.050	V	1
Overcharge release voltage	Vcl	V _{CL} = V _{CU}	V _{CL} - 0.020	Vcl	V _{CL} + 0.015	V	1
Overdischarge detection voltage	VDL	-	V _{DL} - 0.050	V _{DL}	V _{DL} + 0.050	V	2
		V _{DL} ≠ V _{DU}	V _{DU} - 0.075	Vdu	V _{DU} + 0.075	V	2
Overdischarge release voltage	Vdu	V _{DL} = V _{DU}	V _{DU} - 0.050	Vdu	V _{DU} + 0.050	V	2
Discharge overcurrent 1 detection voltage	V _{DIOV1}	-	V _{DIOV1} - 1.5	V _{DIOV1}	V _{DIOV1} + 1.5	mV	5
Discharge overcurrent 2 detection voltage	V _{DIOV2}	-	V _{DIOV2} - 3	V _{DIOV2}	V _{DIOV2} + 3	mV	2
l and shout sinculting data tion walters		$20 \text{ mV} \le \text{V}_{\text{SHORT}} \le 100 \text{ mV}$	Vshort - 5	VSHORT	V _{SHORT} + 5	mV	2
Load short-circuiting detection voltage	VSHORT	$101 \text{ mV} \le \text{V}_{\text{SHORT}} \le 300 \text{ mV}$	V _{SHORT} - 10	VSHORT	V _{SHORT} + 10	mV	2
Charge overcurrent detection voltage	VCIOV	-	V _{CIOV} - 1.5	VCIOV	V _{CIOV} + 1.5	mV	2
Discharge overcurrent release voltage	V _{RIOV}	V _{DD} = 3.4 V	V _{DD} × 0.77	V _{DD} × 0.80	V _{DD} × 0.83	V	5
0 V Battery Charge							
0 V battery charge starting charger voltage	V _{0CHA}	0 V battery charge enabled	0.7	1.1	1.5	V	4
0 V battery charge inhibition battery voltage	VOINH	0 V battery charge inhibited	1.0	1.2	1.4	V	2
Internal Resistance							
Resistance between VDD pin and VM pin	R _{VMD}	V _{DD} = 1.8 V, V _{VM} = 0 V	500	1250	2500	kΩ	3
Resistance between VM pin and VSS pin	R _{VMS}	V _{DD} = 3.4 V, V _{VM} = 1.0 V	5	10	15	kΩ	3
Input Voltage	1					1	
Operation voltage between	V _{DSOP1}	_	1.5	_	6.0	v	_
VDD pin and VSS pin	V DOOFT				0.0		
Operation voltage between	V _{DSOP2}	-	1.5	-	28	v	-
VDD pin and VM pin	1 2001 2					-	
Input Current	i.						
Current consumption during operation	I _{OPE}	$V_{DD} = 3.4 \text{ V}, V_{VM} = 0 \text{ V}$	-	2.0	4.0	μA	3
Current consumption during power-down	PDN	$V_{DD} = V_{VM} = 1.5 V$	-	-	0.05	μA	3
Current consumption during overdischarge	IOPED	$V_{DD} = V_{VM} = 1.5 V$	-	-	0.5	μA	3
Output Resistance		i		40		1.0	4
CO pin resistance "H"	R _{COH}	-	5	10	20	kΩ	4
CO pin resistance "L"	RCOL	-	1.5	3	6	kΩ	4
DO pin resistance "H"	R _{DOH}	-	5	10	20	kΩ	4
DO pin resistance "L"	Rdol	-	1	2	4	kΩ	4
Delay Time		1	t v 0 7	4	1 1 1 2	1	
Overcharge detection delay time Overdischarge detection delay time	tcu	-	t _{CU} × 0.7	tcu	t _{CU} × 1.3	-	5
	t _{DL}	-	t _{DL} × 0.7	t _{DL}	t _{DL} × 1.3	-	5
Discharge overcurrent 1 detection delay time	t _{DIOV1}	-	t _{DIOV1} × 0.75	t _{DIOV1}	t _{DIOV1} × 1.25	-	5
Discharge overcurrent 2 detection							
delay time	t _{DIOV2}	-	t _{DIOV2} × 0.7	t _{DIOV2}	t _{DIOV2} × 1.3	-	5
Load short-circuiting detection delay time	tshort	_	t _{SHORT} × 0.7	tshort	tshort × 1.3	-	5
Charge overcurrent detection delay time	tciov	_	$t_{CIOV} \times 0.7$	tciov	$t_{CIOV} \times 1.3$	-	5

Table 9

2. Ta = -20°C to +60°C^{*1}

(Ta = -20° C to $+60^{\circ}$ C^{*1} unless otherwise specified) Test Item Symbol Condition Min. Typ. Max. Unit Circuit Detection Voltage Vcu Vcu - 0.020 Vcu V_{CU} + 0.020 V 1 Overcharge detection voltage -V_{CL} + 0.057 1 V_{CL} ≠ V_{CU} V_{CL} - 0.065 V_{CL} V Vcl Overcharge release voltage Vcl = Vcu V_{CL} - 0.025 Vcl V_{CL} + 0.020 V 1 VDL V_{DL} - 0.060 V_{DL} V_{DL} + 0.055 V 2 Overdischarge detection voltage V_{DU} - 0.085 V_{DU} + 0.080 V 2 Vdl ≠ Vdu Vdu Vdu Overdischarge release voltage $V_{DL} = V_{DU}$ V_{DU} - 0.060 V_{DU} V_{DU} + 0.055 V 2 Discharge overcurrent 1 detection voltage VDIOV1 _ VDIOV1 - 2 VDIOV1 $V_{DIOV1} + 2$ mV 5 Discharge overcurrent 2 detection voltage V_{DIOV2} + 3 mV 2 VDIOV2 VDIOV2 - 3 VDIOV2 _ VSHORT - 5 $20 \text{ mV} \leq \text{V}_{\text{SHORT}} \leq 100 \text{ mV}$ VSHORT + 5 mV 2 VSHORT VSHORT Load short-circuiting detection voltage V_{SHORT} + 10 mV 2 $101 \text{ mV} \le \text{V}_{\text{SHORT}} \le 300 \text{ mV}$ VSHORT - 10 VSHORT Vciov 2 Charge overcurrent detection voltage Vciov Vciov - 2 V_{CIOV} + 2 mV - $V_{DD} \times$ VDD × 0.77 Discharge overcurrent release voltage VRIOV V_{DD} = 3.4 V V_{DD} × 0.83 V 5 0.80 0 V Battery Charge 0 V battery charge starting charger voltage Vосна 0 V battery charge enabled 0.5 1.1 1.7 V 4 V 2 0 V battery charge inhibition battery voltage VOINH 0 V battery charge inhibited 1.0 1.2 1.4 Internal Resistance Resistance between VDD pin and VM pin **R**_{VMD} V_{DD} = 1.8 V, V_{VM} = 0 V 250 1250 3500 kΩ 3 Resistance between VM pin and VSS pin **R**vms $V_{DD} = 3.4 V, V_{VM} = 1.0 V$ 3.5 10 20 kΩ 3 Input Voltage Operation voltage between V VDSOP1 1.5 6.0 --VDD pin and VSS pin Operation voltage between VDSOP2 1.5 28 V _ _ _ VDD pin and VM pin Input Current $V_{DD} = 3.4 \text{ V}, V_{VM} = 0 \text{ V}$ Current consumption during operation IOPE 2.0 5.0 μA 3 -Current consumption during power-down Vpp = Vvм = 1.5 V 3 PDN 0.1 uА -- $V_{DD} = V_{VM} = 1.5 V$ 1.0 μA Current consumption during overdischarge IOPED 3 -_ Output Resistance Rcoн kΩ CO pin resistance "H" 2.5 30 4 10 RCOL CO pin resistance "L" 0.75 3 9 kΩ 4 _ DO pin resistance "H" Rdoh 30 4 2.5 10 kΩ -DO pin resistance "L" RDOL 0.5 2 6 kΩ 4 _ Delay Time t_{CU} × 0.6 Overcharge detection delay time t_{CU} × 1.4 5 tcu tcu -Overdischarge detection delay time t_{DL} × 0.6 t_{DL} × 1.4 5 t_{DL} t_{DL} -Discharge overcurrent 1 detection t_{DIOV1} t_{DIOV1} × 0.65 t_{DIOV1} × 1.35 5 t_{DIOV1} _ delay time Discharge overcurrent 2 detection 5 $t_{DIOV2} \times 0.6$ t_{DIOV2} t_{DIOV2} $t_{DIOV2} \times 1.4$ _ delay time Load short-circuiting detection delay time t_{SHORT} × 0.6 **t**SHORT t_{SHORT} × 1.4 5 tshort --Charge overcurrent detection delay time $t_{CIOV} \times 0.6$ $t_{CIOV} \times 1.4$ -5 tciov tciov

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Table 10

3. Ta = -40°C to +85°C^{*1}

(Ta = -40° C to $+85^{\circ}$ C^{*1} unless otherwise specified) Test Item Symbol Condition Min. Typ. Max. Unit Circuit Detection Voltage Vcu V_{CU} - 0.040 Vcu V_{CU} + 0.028 V 1 Overcharge detection voltage -V_{CL} + 0.060 1 V_{CL} ≠ V_{CU} V_{CL} - 0.075 V_{CL} V Vcl Overcharge release voltage Vcl = Vcu V_{CL} - 0.045 Vcl V_{CL} + 0.028 V 1 VDL V_{DL} - 0.070 V_{DL} V_{DL} + 0.060 V 2 Overdischarge detection voltage V_{DU} - 0.095 V_{DU} + 0.085 V 2 Vdl ≠ Vdu Vdu VDU Overdischarge release voltage $V_{DL} = V_{DU}$ V_{DU} - 0.070 Vdu V_{DU} + 0.060 V 2 Discharge overcurrent 1 detection voltage VDIOV1 _ VDIOV1 - 2 VDIOV1 $V_{DIOV1} + 2$ mV 5 Discharge overcurrent 2 detection voltage V_{DIOV2} + 3 mV 2 VDIOV2 VDIOV2 - 3 VDIOV2 _ VSHORT - 5 $20 \text{ mV} \leq \text{V}_{\text{SHORT}} \leq 100 \text{ mV}$ VSHORT + 5 mV 2 VSHORT VSHORT Load short-circuiting detection voltage 101 mV ≤ V_{SHORT} <u>≤ 300 mV</u> VSHORT - 10 VSHORT + 10 mV 2 VSHORT 2 Charge overcurrent detection voltage Vciov Vciov - 2 Vciov V_{CIOV} + 2 mV - $V_{DD} \times$ V_{DD} × 0.77 5 Discharge overcurrent release voltage VRIOV V_{DD} = 3.4 V V_{DD} × 0.83 V 0.80 0 V Battery Charge 0 V battery charge starting charger voltage Vосна 0 V battery charge enabled 0.5 1.1 1.7 V 4 V 2 0 V battery charge inhibition battery voltage VOINH 0 V battery charge inhibited 1.0 1.2 1.4 Internal Resistance Resistance between VDD pin and VM pin **R**_{VMD} V_{DD} = 1.8 V, V_{VM} = 0 V 250 1250 3500 kΩ 3 Resistance between VM pin and VSS pin **R**vms $V_{DD} = 3.4 V, V_{VM} = 1.0 V$ 3.5 10 20 kΩ 3 Input Voltage Operation voltage between VDSOP1 V 1.5 6.0 _ -VDD pin and VSS pin Operation voltage between VDSOP2 1.5 28 V _ _ _ VDD pin and VM pin Input Current $V_{DD} = 3.4 \text{ V}, V_{VM} = 0 \text{ V}$ Current consumption during operation IOPE 2.0 5.0 μA 3 -Current consumption during power-down Vpp = Vvм = 1.5 V 3 PDN 0.1 uА --Current consumption during overdischarge IOPED $V_{DD} = V_{VM} = 1.5 V$ 1.0 μA 3 -_ Output Resistance Rcoн kΩ CO pin resistance "H" 2.5 30 4 10 RCOL CO pin resistance "L" 0.75 3 9 kΩ 4 _ DO pin resistance "H" Rdoh 10 30 kΩ 4 2.5 _ DO pin resistance "L" RDOL 0.5 2 6 kΩ 4 _ Delay Time t_{CU} × 0.4 Overcharge detection delay time tcu × 1.6 5 tcu tcu -Overdischarge detection delay time t_{DL} × 0.4 t_{DL} × 1.6 5 t_{DL} t_{DL} -Discharge overcurrent 1 detection t_{DIOV1} $t_{DIOV1} \times 0.4$ t_{DIOV1} × 1.6 5 t_{DIOV1} _ delay time Discharge overcurrent 2 detection 5 t_{DIOV2} $t_{DIOV2} \times 0.4$ t_{DIOV2} t_{DIOV2} × 1.6 _ delay time Load short-circuiting detection delay time t_{SHORT} × 0.4 tshort × 1.6 5 tshort **t**SHORT - $t_{CIOV} \times 0.4$ Charge overcurrent detection delay time $t_{CIOV} \times 1.6$ -5 tciov tciov

Table 11

4. Ta = -40°C to +105°C^{*1}

(Ta = -40° C to $+105^{\circ}$ C^{*1} unless otherwise specified) Test Item Symbol Condition Min. Typ. Max. Unit Circuit Detection Voltage Vcu V_{CU} - 0.042 Vcu $V_{CU} + 0.030$ V 1 Overcharge detection voltage -V_{CL} + 0.060 1 V_{CL} ≠ V_{CU} V_{CL} - 0.077 V_{CL} V Vcl Overcharge release voltage Vcl = Vcu V_{CL} - 0.047 Vcl V_{CL} + 0.030 V 1 VDL V_{DL} - 0.075 V_{DL} V_{DL} + 0.060 V 2 Overdischarge detection voltage V_{DU} - 0.100 V_{DU} + 0.085 V 2 Vdl ≠ Vdu Vdu Vdu Overdischarge release voltage $V_{DL} = V_{DU}$ V_{DU} - 0.075 V_{DU} V_{DU} + 0.060 V 2 Discharge overcurrent 1 detection voltage VDIOV1 VDIOV1 - 2.5 VDIOV1 VDIOV1 + 2.5 mV 5 _ Discharge overcurrent 2 detection voltage V_{DIOV2} - 4.5 V_{DIOV2} + 4.5 mV 2 VDIOV2 VDIOV2 _ $20 \text{ mV} \leq \text{V}_{\text{SHORT}} \leq 100 \text{ mV}$ VSHORT - 6 VSHORT + 6 mV 2 VSHORT VSHORT Load short-circuiting detection voltage VSHORT - 10 VSHORT + 10 mV 2 $101 \text{ mV} \le \text{V}_{\text{SHORT}} \le 300 \text{ mV}$ VSHORT 2 Charge overcurrent detection voltage Vciov Vciov - 2.5 Vciov Vciov + 2.5 mV - $V_{DD} \times$ VDD × 0.77 Discharge overcurrent release voltage VRIOV V_{DD} = 3.4 V V_{DD} × 0.83 V 5 0.80 0 V Battery Charge 0 V battery charge starting charger voltage Vосна 0 V battery charge enabled 0.4 1.1 1.8 V 4 V 2 0 V battery charge inhibition battery voltage VOINH 0 V battery charge inhibited 1.0 1.2 1.4 Internal Resistance Resistance between VDD pin and VM pin **R**_{VMD} V_{DD} = 1.8 V, V_{VM} = 0 V 250 1250 3500 kΩ 3 Resistance between VM pin and VSS pin **R**vms $V_{DD} = 3.4 V, V_{VM} = 1.0 V$ 3.5 10 20 kΩ 3 Input Voltage Operation voltage between V VDSOP1 1.5 6.0 --VDD pin and VSS pin Operation voltage between VDSOP2 1.5 28 V _ _ _ VDD pin and VM pin Input Current $V_{DD} = 3.4 \text{ V}, \text{ V}_{VM} = 0 \text{ V}$ Current consumption during operation IOPE 2.0 5.0 μA 3 -Current consumption during power-down Vpp = Vvм = 1.5 V 3 PDN 0.5 uА -- $V_{DD} = V_{VM} = 1.5 V$ 1.0 μA Current consumption during overdischarge IOPED 3 -_ Output Resistance Rcoн kΩ CO pin resistance "H" 2.5 30 4 10 CO pin resistance "L" RCOL 0.75 3 9 kΩ 4 _ DO pin resistance "H" Rdoh 30 4 2.5 10 kΩ -DO pin resistance "L" RDOL 0.5 2 6 kΩ 4 _ Delay Time Overcharge detection delay time t_{CU} × 0.35 tcu × 1.65 5 tcu tcu -Overdischarge detection delay time t_{DL} × 0.35 t_{DL} × 1.65 5 t_{DL} t_{DL} -Discharge overcurrent 1 detection t_{DIOV1} t_{DIOV1} × 0.35 t_{DIOV1} × 1.65 5 t_{DIOV1} _ delay time Discharge overcurrent 2 detection 5 t_{DIOV2} × 0.35 t_{DIOV2} t_{DIOV2} t_{DIOV2} × 1.65 _ delay time Load short-circuiting detection delay time tSHORT × 0.35 tshort × 1.65 5 tshort **t**SHORT --Charge overcurrent detection delay time $t_{CIOV} \times 0.35$ tciov × 1.65 -5 tciov tciov

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Table 12

5. Ta = -40°C to +125°C^{*1}

(Ta = -40° C to $+125^{\circ}$ C^{*1} unless otherwise specified) Test Item Symbol Condition Min. Typ. Max. Unit Circuit Detection Voltage Vcu V_{CU} - 0.045 Vcu $V_{CU} + 0.030$ V 1 Overcharge detection voltage -V_{CL} + 0.060 1 V_{CL} ≠ V_{CU} V_{CL} - 0.080 V_{CL} V Vcl Overcharge release voltage Vcl = Vcu V_{CL} - 0.050 Vcl V_{CL} + 0.030 V 1 VDL V_{DL} - 0.080 V_{DL} V_{DL} + 0.060 V 2 Overdischarge detection voltage V_{DU} - 0.105 V_{DU} + 0.085 V 2 Vdl ≠ Vdu Vdu VDU Overdischarge release voltage $V_{DL} = V_{DU}$ V_{DU} - 0.080 V_{DU} V_{DU} + 0.060 V 2 Discharge overcurrent 1 detection voltage VDIOV1 _ VDIOV1 - 2.5 VDIOV1 $V_{DIOV1} + 4$ mV 5 Discharge overcurrent 2 detection voltage V_{DIOV2} - 4.5 V_{DIOV2} + 4.5 mV 2 VDIOV2 VDIOV2 _ $20 \text{ mV} \leq \text{V}_{\text{SHORT}} \leq 100 \text{ mV}$ VSHORT - 6 VSHORT + 6 mV 2 VSHORT VSHORT Load short-circuiting detection voltage 101 mV ≤ V_{SHORT} <u>≤ 300 mV</u> VSHORT - 10 VSHORT + 10 mV 2 VSHORT 2 Charge overcurrent detection voltage Vciov Vciov - 4 Vciov Vciov + 2.5 mV - $V_{DD} \times$ V_{DD} × 0.83 V_{DD} × 0.77 5 Discharge overcurrent release voltage VRIOV $V_{DD} = 3.4 V$ V 0.80 0 V Battery Charge 0 V battery charge starting charger voltage Vосна 0 V battery charge enabled 0.4 1.1 1.8 V 4 V 2 0 V battery charge inhibition battery voltage VOINH 0 V battery charge inhibited 1.0 1.2 1.4 Internal Resistance Resistance between VDD pin and VM pin **R**_{VMD} V_{DD} = 1.8 V, V_{VM} = 0 V 250 1250 3500 kΩ 3 Resistance between VM pin and VSS pin **R**vms $V_{DD} = 3.4 V, V_{VM} = 1.0 V$ 3.5 10 20 kΩ 3 Input Voltage Operation voltage between VDSOP1 V 1.5 6.0 _ -VDD pin and VSS pin Operation voltage between VDSOP2 1.5 28 V _ _ _ VDD pin and VM pin Input Current $V_{DD} = 3.4 \text{ V}, \text{ V}_{VM} = 0 \text{ V}$ Current consumption during operation IOPE 2.0 5.0 μA 3 -Current consumption during power-down Vpp = Vvм = 1.5 V 3 PDN 0.5 uА --1.0 $V_{DD} = V_{VM} = 1.5 V$ μA Current consumption during overdischarge IOPED 3 -_ Output Resistance Rcoн kΩ CO pin resistance "H" 2.5 30 4 10 RCOL CO pin resistance "L" 0.75 3 9 kΩ 4 _ DO pin resistance "H" Rdoh 10 30 kΩ 4 2.5 -DO pin resistance "L" RDOL 0.5 2 6 kΩ 4 _ Delay Time t_{CU} × 0.3 Overcharge detection delay time t_{CU} × 1.7 5 tcu tcu -Overdischarge detection delay time t_{DL} t_{DL} × 0.3 t_{DL} × 1.7 5 t_{DL} -Discharge overcurrent 1 detection t_{DIOV1} $t_{DIOV1} \times 0.3$ t_{DIOV1} × 1.7 5 t_{DIOV1} _ delay time Discharge overcurrent 2 detection 5 $t_{DIOV2} \times 0.3$ t_{DIOV2} t_{DIOV2} t_{DIOV2} × 1.7 _ delay time Load short-circuiting detection delay time t_{SHORT} × 0.3 **t**SHORT tshort × 1.7 5 tshort --Charge overcurrent detection delay time $t_{CIOV} \times 0.3$ $t_{CIOV} \times 1.7$ -5 tciov tciov

Test Circuits

Caution Unless otherwise specified, the output voltage levels "H" and "L" at CO pin (V_{CO}) and DO pin (V_{DO}) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the CO pin level with respect to V_{VM} and the DO pin level with respect to V_{SS}.

1. Overcharge detection voltage, overcharge release voltage (Test circuit 1)

1.1 $V_{CU} \neq V_{CL}$ (Product in which overcharge release voltage differs from overcharge detection voltage)

Overcharge detection voltage (V_{CU}) is defined as the voltage V1 at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually increased after setting V1 = 3.4 V, V2 = 0 V. Overcharge release voltage (V_{CL}) is defined as the voltage V1 at which V_{CO} goes from "L" to "H" when the voltage V1 is then gradually decreased. Overcharge hysteresis voltage (V_{HC}) is defined as the difference between V_{CL} and V_{CL}.

1.2 V_{CU} = V_{CL} (Product in which overcharge release voltage is the same as overcharge detection voltage)

Overcharge detection voltage (V_{CU}) is defined as the voltage V1 at which V_{CO} goes from "H" to "L" when the voltage V1 is gradually increased after setting V1 = 3.4 V, V2 = 0 V. Overcharge release voltage (V_{CL}) is defined as the voltage V1 at which V_{CO} goes from "L" to "H" when setting V2 = 0.4 V and when the voltage V1 is then gradually decreased. Overcharge hysteresis voltage (V_{HC}) is defined as the difference between V_{CU} and V_{CL}.

2. Overdischarge detection voltage, overdischarge release voltage (Test circuit 2)

Overdischarge detection voltage (V_{DL}) is defined as the voltage V1 at which V_{DO} goes from "H" to "L" when the voltage V1 is gradually decreased after setting V1 = 3.4 V, V2 = 0 V. Overdischarge release voltage (V_{DU}) is defined as the voltage V1 at which V_{DO} goes from "L" to "H" when setting V2 = 0.01 V and when the voltage V1 is then gradually increased. Overdischarge hysteresis voltage (V_{HD}) is defined as the difference between V_{DU} and V_{DL} .

3. Discharge overcurrent 1 detection voltage, discharge overcurrent release voltage (Test circuit 5)

Discharge overcurrent 1 detection voltage (V_{DIOV1}) is defined as the voltage V2 at which delay time from when V2 is increased after setting V1 = 3.4 V, V2 = 0 V to when V_{DO} goes from "H" to "L" is discharge overcurrent 1 detection delay time (t_{DIOV1}). Discharge overcurrent release voltage (V_{RIOV}) is defined as the voltage V2 at which V_{DO} goes from "L" to "H" when setting V2 = 3.4 V and when the voltage V2 is then gradually decreased.

When the voltage V2 falls below V_{RIOV} , V_{DO} will go to "H" after 1.0 ms typ. and maintain "H" during load short-circuiting detection delay time (t_{SHORT}).

4. Discharge overcurrent 2 detection voltage (Test circuit 2)

Discharge overcurrent 2 detection voltage (V_{DIOV2}) is defined as the voltage V2 at which delay time from when V2 is increased after setting V1 = 3.4 V, V2 = 0 V to when V_{DO} goes from "H" to "L" is discharge overcurrent 2 detection delay time (t_{DIOV2}).

5. Load short-circuiting detection voltage (Test circuit 2)

Load short-circuiting detection voltage (V_{SHORT}) is defined as the voltage V2 at which delay time from when V2 is increased after setting V1 = 3.4 V, V2 = 0 V to when V_{DO} goes from "H" to "L" is t_{SHORT} .

6. Charge overcurrent detection voltage (Test circuit 2)

Charge overcurrent detection voltage (V_{CIOV}) is defined as the voltage V2 at which delay time from when V2 is decreased after setting V1 = 3.4 V, V2 = 0 V to when V_{CO} goes from "H" to "L" is charge overcurrent detection delay time (t_{CIOV}).

7. Current consumption during operation (Test circuit 3)

The current consumption during operation (I_{OPE}) is the current that flows through the VDD pin (I_{DD}) under the set conditions of V1 = 3.4 V, V2 = 0 V.

8. Current consumption during power-down, current consumption during overdischarge (Test circuit 3)

8.1 With power-down function

The current consumption during power-down (I_{PDN}) is I_{DD} under the set conditions of V1 = V2 = 1.5 V.

8.2 Without power-down function

The current consumption during overdischarge (IOPED) is IDD under the set conditions of V1 = V2 = 1.5 V.

9. Resistance between VDD pin and VM pin (Test circuit 3)

 R_{VMD} is the resistance between VDD pin and VM pin under the set conditions of V1 = 1.8 V, V2 = 0 V.

10. Resistance between VM pin and VSS pin (Test circuit 3)

 R_{VMS} is the resistance between VM pin and VSS pin under the set conditions of V1 = 3.4 V, V2 = 1.0 V.

11. CO pin resistance "H" (Test circuit 4)

The CO pin resistance "H" (R_{COH}) is the resistance between VDD pin and CO pin under the set conditions of V1 = 3.4 V, V2 = 0 V, V3 = 3.0 V.

12. CO pin resistance "L" (Test circuit 4)

The CO pin resistance "L" (R_{COL}) is the resistance between VM pin and CO pin under the set conditions of V1 = 4.7 V, V2 = 0 V, V3 = 0.4 V.

13. DO pin resistance "H" (Test circuit 4)

The DO pin resistance "H" (R_{DOH}) is the resistance between VDD pin and DO pin under the set conditions of V1 = 3.4 V, V2 = 0 V, V4 = 3.0 V.

14. DO pin resistance "L" (Test circuit 4)

The DO pin resistance "L" (R_{DOL}) is the resistance between VSS pin and DO pin under the set conditions of V1 = 1.8 V, V2 = 0 V, V4 = 0.4 V.

15. Overcharge detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 0 V, the voltage V1 is increased. The time interval from when the voltage V1 exceeds V_{CU} until V_{CO} goes to "L" is the overcharge detection delay time (t_{CU}).

16. Overdischarge detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 0 V, the voltage V1 is decreased. The time interval from when the voltage V1 falls below V_{DL} until V_{DO} goes to "L" is the overdischarge detection delay time (t_{DL}).

17. Discharge overcurrent 1 detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 0 V, the voltage V2 is increased. The time interval from when the voltage V2 exceeds V_{DIOV1} until V_{DO} goes to "L" is the discharge overcurrent 1 detection delay time (t_{DIOV1}).

18. Discharge overcurrent 2 detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 0 V, the voltage V2 is increased. The time interval from when the voltage V2 exceeds V_{DIOV2} until V_{DO} goes to "L" is the discharge overcurrent 2 detection delay time (t_{DIOV2}).

19. Load short-circuiting detection delay time (Test circuit 5)

After setting V1 = 3.4 V, V2 = 0 V, the voltage V2 is increased. The time interval from when the voltage V2 exceeds V_{SHORT} until V_{D0} goes to "L" is the load short-circuiting detection delay time (t_{SHORT}).

20. Charge overcurrent detection delay time (Test circuit 5)

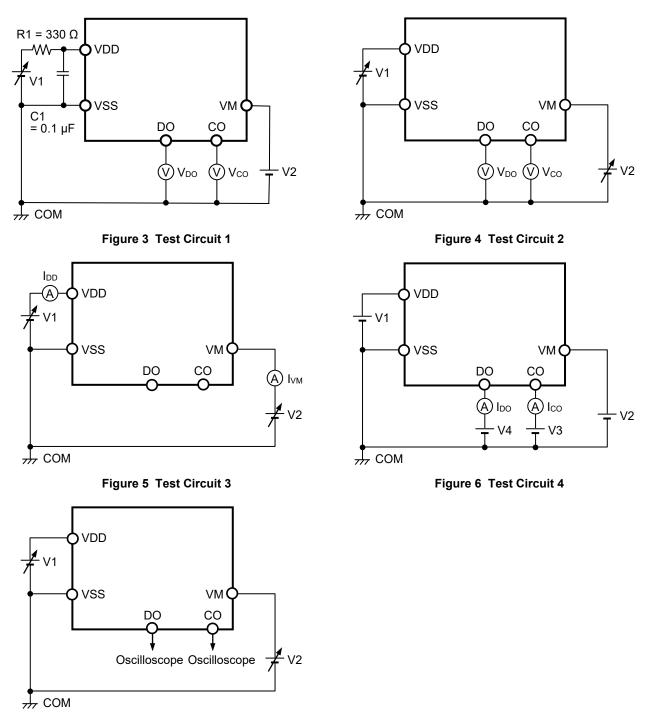
After setting V1 = 3.4 V, V2 = 0 V, the voltage V2 is decreased. The time interval from when the voltage V2 falls below V_{CIOV} until V_{CO} goes to "L" is the charge overcurrent detection delay time (t_{CIOV}).

21. 0 V battery charge starting charger voltage (0 V battery charge enabled) (Test circuit 4)

The 0 V battery charge starting charger voltage (V_{0CHA}) is defined as the absolute value of voltage V2 at which the current flowing through the CO pin (I_{CO}) exceeds 1.0 μ A when the voltage V2 is gradually decreased after setting V1 = 0 V, V2 = V3 = -0.5 V.

22. 0 V battery charge inhibition battery voltage (0 V battery charge inhibited) (Test circuit 2)

The 0 V battery charge inhibition battery voltage (V_{0INH}) is defined as the voltage V1 at which V_{CO} goes to "L" ($V_{CO} = V_{VM}$) when the voltage V1 is gradually decreased after setting V1 = 1.8 V, V2 = -2.0 V.





Operation

Remark Refer to "**Battery Protection IC Connection Example**".

1. Normal status

This IC monitors the voltage of the battery connected between VDD pin and VSS pin, and the voltage between VM pin and VSS pin to control charging and discharging. When the battery voltage is in the range from overdischarge detection voltage (V_{DL}) to overcharge detection voltage (V_{CU}), the VM pin voltage is in the range from charge overcurrent detection voltage (V_{CIOV}) to discharge overcurrent 1 detection voltage (V_{DIOV1}), both charge and discharge control FETs are turned on. This status is called the normal status, and in this condition charging and discharging can be carried out freely. The resistance between VDD pin and VM pin (R_{VMD}), and the resistance between VM pin and VSS pin (R_{VMS}) are not connected in the normal status.

Caution After the battery is connected, discharging may not be carried out. In this case, this IC returns to the normal status by connecting a charger.

2. Overcharge status

2.1 V_{CL} ≠ V_{CU} (Product in which overcharge release voltage differs from overcharge detection voltage)

When the battery voltage becomes higher than V_{CU} during charging in the normal status and the condition continues for the overcharge detection delay time (t_{CU}) or longer, the charge control FET is turned off and charging is stopped. This status is called the overcharge status.

The overcharge status is released in the following two cases.

- (1) In the case that the VM pin voltage is lower than 0.35 V typ., this IC releases the overcharge status when the battery voltage falls below overcharge release voltage (V_{CL}).
- (2) In the case that the VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage falls below V_{CU}.

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the V_f voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage is equal to or lower than V_{CU} .

Caution If the battery is charged to a voltage higher than V_{cu} and the battery voltage does not fall below V_{cu} even when a heavy load is connected, discharge overcurrent detection and load short-circuiting detection do not function until the battery voltage falls below V_{cu}. Since an actual battery has an internal impedance of tens of m Ω , the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.

2. 2 V_{CL} = V_{CU} (Product in which overcharge release voltage is the same as overcharge detection voltage)

When the battery voltage becomes higher than V_{CU} during charging in the normal status and the condition continues for t_{CU} or longer, the charge control FET is turned off and charging is stopped. This status is called the overcharge status.

In the case that the VM pin voltage is equal to or higher than 0.35 V typ. and the battery voltage falls below V_{CU} , this IC releases the overcharge status.

When the discharge is started by connecting a load after the overcharge detection, the VM pin voltage rises by the V_f voltage of the internal parasitic diode than the VSS pin voltage, because the discharge current flows through the parasitic diode in the charge control FET. If this VM pin voltage is equal to or higher than 0.35 V typ., this IC releases the overcharge status when the battery voltage is equal to or lower than V_{CU} .

- Caution 1. If the battery is charged to a voltage higher than V_{CU} and the battery voltage does not fall below V_{CU} even when a heavy load is connected, discharge overcurrent detection and load shortcircuiting detection do not function until the battery voltage falls below V_{CU} . Since an actual battery has an internal impedance of tens of m Ω , the battery voltage drops immediately after a heavy load that causes overcurrent is connected, and discharge overcurrent detection and load short-circuiting detection function.
 - 2. When a charger is connected after overcharge detection, the overcharge status is not released even if the battery voltage is below V_{CL} . The overcharge status is released when the discharge current flows and the VM pin voltage goes over 0.35 V typ. by removing the charger.

3. Overdischarge status

When the battery voltage falls below V_{DL} during discharging in the normal status and the condition continues for the overdischarge detection delay time (t_{DL}) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the overdischarge status.

Under the overdischarge status, VDD pin and VM pin are shorted by R_{VMD} in this IC. The VM pin voltage is pulled up by R_{VMD} .

When connecting a charger in the overdischarge status, the battery voltage reaches V_{DL} or higher and this IC releases the overdischarge status if the VM pin voltage is below 0 V typ.

The battery voltage reaches the overdischarge release voltage (V_{DU}) or higher and this IC releases the overdischarge status if the VM pin voltage is not below 0 V typ.

R_{VMS} is not connected in the overdischarge status.

3.1 With power-down function

Under the overdischarge status, when the VM pin voltage is 0.7 V typ. or higher, the power-down function works and the current consumption is reduced to the current consumption during power-down (I_{PDN}). By connecting a battery charger, the power-down function is released when the VM pin voltage is 0.7 V typ. or lower.

- When a battery is not connected to a charger and the VM pin voltage ≥ 0.7 V typ., this IC maintains the overdischarge status even when the battery voltage reaches V_{DU} or higher.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches V_{DU} or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ. ≥ the VM pin voltage, the battery voltage reaches V_{DL} or higher and this IC releases the overdischarge status.

3.2 Without power-down function

Under the overdischarge status, the power-down function does not work even when the VM pin voltage is 0.7 V typ. or higher.

- When a battery is not connected to a charger and the VM pin voltage ≥ 0.7 V typ., the battery voltage reaches V_{DU} or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0.7 V typ. > the VM pin voltage > 0 V typ., the battery voltage reaches V_{DU} or higher and this IC releases the overdischarge status.
- When a battery is connected to a charger and 0 V typ. ≥ the VM pin voltage, the battery voltage reaches V_{DL} or higher and this IC releases the overdischarge status.

4. Discharge overcurrent status (discharge overcurrent 1, discharge overcurrent 2, load short- circuiting)

When a battery in the normal status is in the status where the VM pin voltage is equal to or higher than V_{DIOV1} because the discharge current is equal to or higher than the specified value and the status continues for the discharge overcurrent 1 detection delay time (t_{DIOV1}) or longer, the discharge control FET is turned off and discharging is stopped. This status is called the discharge overcurrent status.

Under the discharge overcurrent status, VM pin and VSS pin are shorted by R_{VMS} in this IC. However, the VM pin voltage is the VDD pin voltage due to the load as long as the load is connected. When the load is disconnected, VM pin returns to the VSS pin voltage.

When the VM pin voltage returns to V_{RIOV} or lower, this IC releases the discharge overcurrent status. R_{VMD} is not connected in the discharge overcurrent status.

5. Charge overcurrent status

When a battery in the normal status is in the status where the VM pin voltage is equal to or lower than V_{CIOV} because the charge current is equal to or higher than the specified value and the status continues for the charge overcurrent detection delay time (t_{CIOV}) or longer, the charge control FET is turned off and charging is stopped. This status is called the charge overcurrent status.

This IC releases the charge overcurrent status when the discharge current flows and the VM pin voltage is 0.35 V typ. or higher by removing the charger.

The charge overcurrent detection does not function in the overdischarge status.

6. 0 V battery charge enabled

This function is used to recharge a connected battery whose voltage is 0 V due to self-discharge. When the 0 V battery charge starting charger voltage (V_{0CHA}) or a higher voltage is applied between the EB+ and EB- pins by connecting a charger, the charge control FET gate is fixed to the VDD pin voltage.

When the voltage between the gate and source of the charge control FET becomes equal to or higher than the threshold voltage due to the charger voltage, the charge control FET is turned on to start charging. At this time, the discharge control FET is off and the charging current flows through the internal parasitic diode in the discharge control FET. When the battery voltage becomes equal to or higher than V_{DL} , this IC returns to the normal status.

- Caution 1. Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.
 - 2. The 0 V battery charge has higher priority than the charge overcurrent detection function. Consequently, a product in which use of the 0 V battery charge is enabled charges a battery forcibly and the charge overcurrent cannot be detected when the battery voltage is lower than V_{DL} .

7. 0 V battery charge inhibited

This function inhibits charging when a battery that is internally short-circuited (0 V battery) is connected. When the battery voltage is the 0 V battery charge inhibition battery voltage (V_{0INH}) or lower, the charge control FET gate is fixed to the EB- pin voltage to inhibit charging. When the battery voltage is V_{0INH} or higher, charging can be performed.

Caution Some battery providers do not recommend charging for a completely self-discharged lithium-ion rechargeable battery. It depends on the characteristics of the lithium-ion rechargeable battery to be used; therefore, please ask the battery provider to determine whether to enable or inhibit the 0 V battery charge.

8. Delay circuit

The detection delay times are determined by dividing a clock of approximately 4 kHz by the counter.

Remark t_{DIOV1}, t_{DIOV2} and t_{SHORT} start when V_{DIOV1} is detected. When V_{DIOV2} or V_{SHORT} is detected over t_{DIOV2} or t_{SHORT} after the detection of V_{DIOV1}, the discharge control FET is turned off within t_{DIOV2} or t_{SHORT} of each detection.

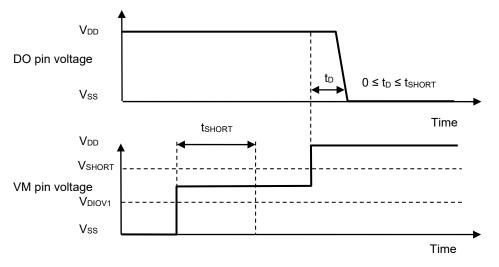
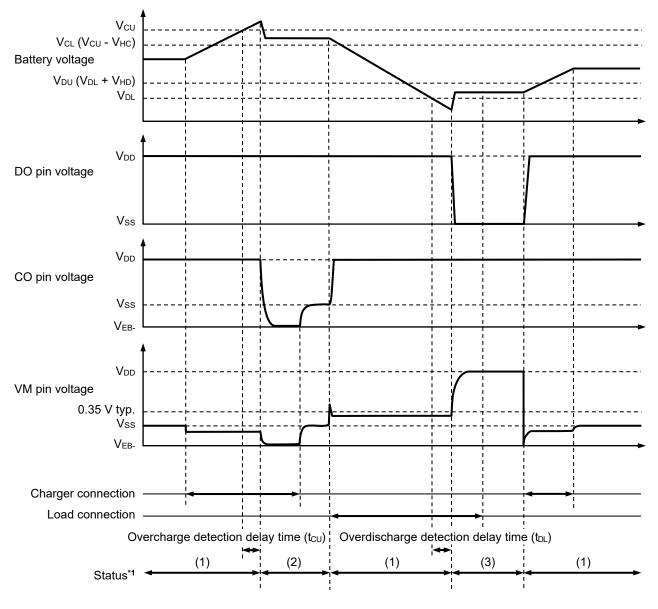


Figure 8

Timing Charts



1. Overcharge detection, overdischarge detection

*1. (1): Normal status

- (2): Overcharge status
- (3): Overdischarge status

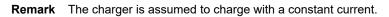
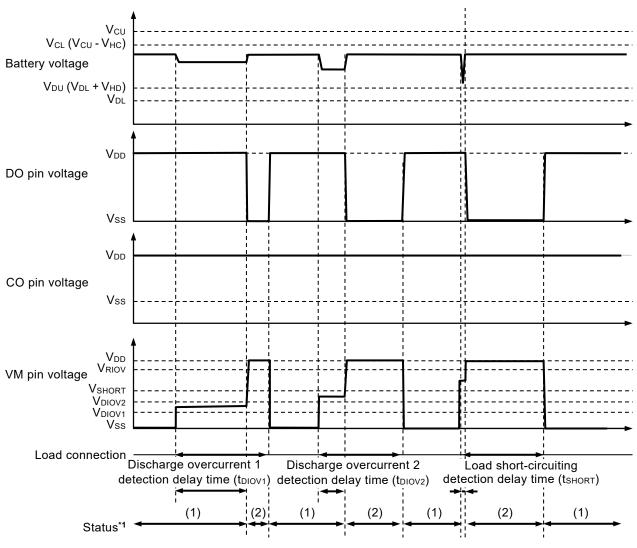


Figure 9



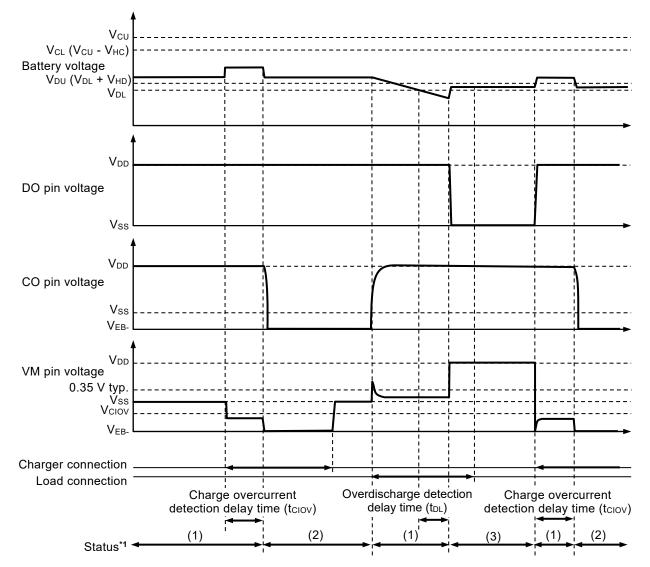
2. Discharge overcurrent detection

*1. (1): Normal status

(2): Discharge overcurrent status

Figure 10

3. Charge overcurrent detection



*1. (1): Normal status

(2): Charge overcurrent status

(3): Overdischarge status

Remark The charger is assumed to charge with a constant current.

Figure 11

Battery Protection IC Connection Example

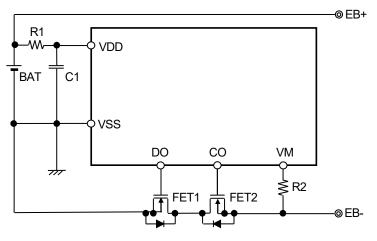


Figure 12

Table 13 Constants for External Components

Symbol	Part	Purpose	Min.	Тур.	Max.	Remark
FET1	N-channel MOS FET	Discharge control	-	-	-	Threshold voltage ≤ Overdischarge detection voltage ^{*1}
FET2	N-channel MOS FET	Charge control	-	-	-	Threshold voltag ≤ Overdischarge detection voltage*¹
R1	Resistor	ESD protection, for power fluctuation	330 Ω	330 Ω	1 kΩ*²	-
C1	Capacitor	For power fluctuation	0.1 µF	0.1 µF	1 μF	-
R2	Resistor	ESD protection, Protection for reverse connection of a charger	270 Ω	470 Ω	1.5 kΩ	-

*1. If a FET with a threshold voltage equal to or higher than the overdischarge detection voltage is used, discharging may be stopped before overdischarge is detected.

*2. Accuracy of overcharge detection voltage is guaranteed by R1 = 330 Ω. Connecting resistors with other values will worsen the accuracy.

Caution 1. The constants may be changed without notice.

2. It has not been confirmed whether the operation is normal or not in circuits other than the connection example. In addition, the connection example and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constants.

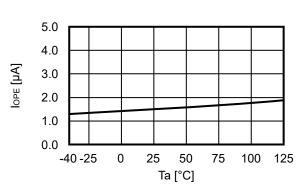
Precautions

- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

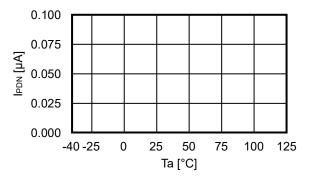
■ Characteristics (Typical Data)

1. Current consumption

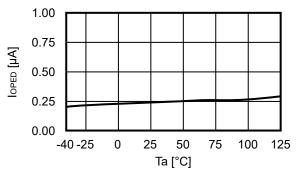
1.1 IOPE vs. Ta



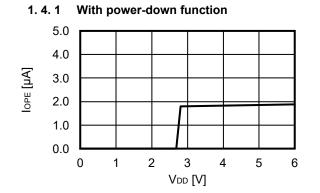
1.2 IPDN VS. Ta



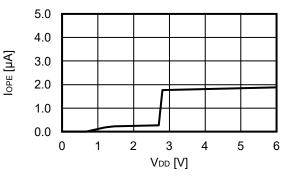
1.3 IOPED VS. Ta

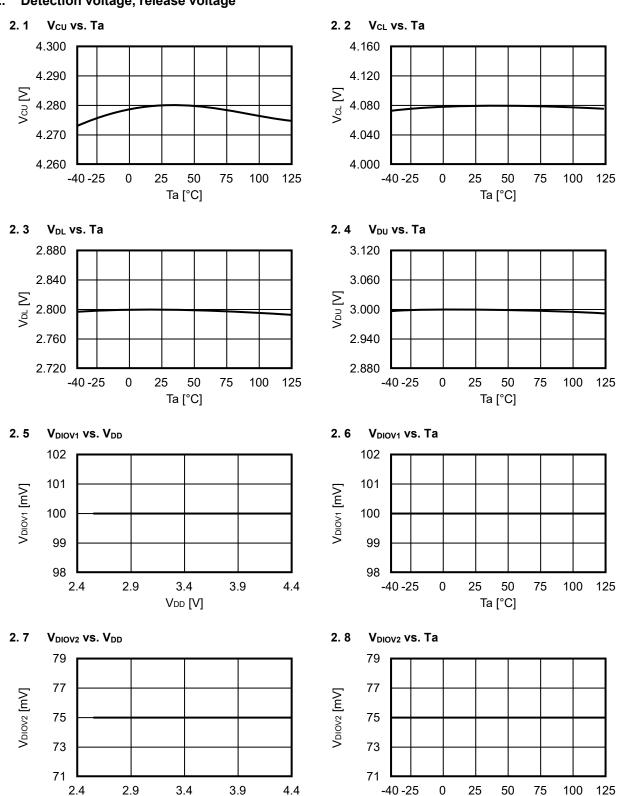


1.4 IOPE VS. VDD



1. 4. 2 Without power-down function

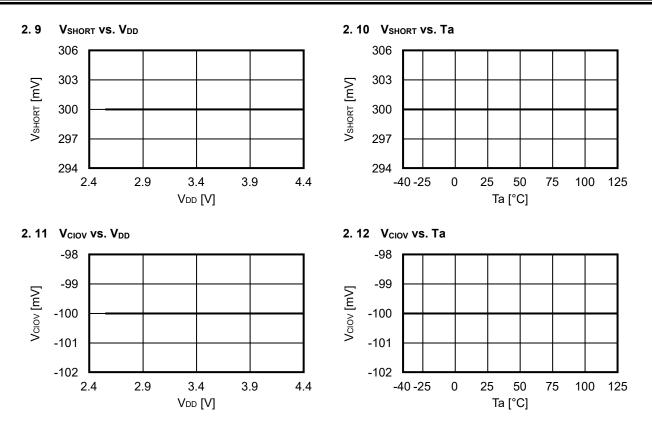




2. Detection voltage, release voltage

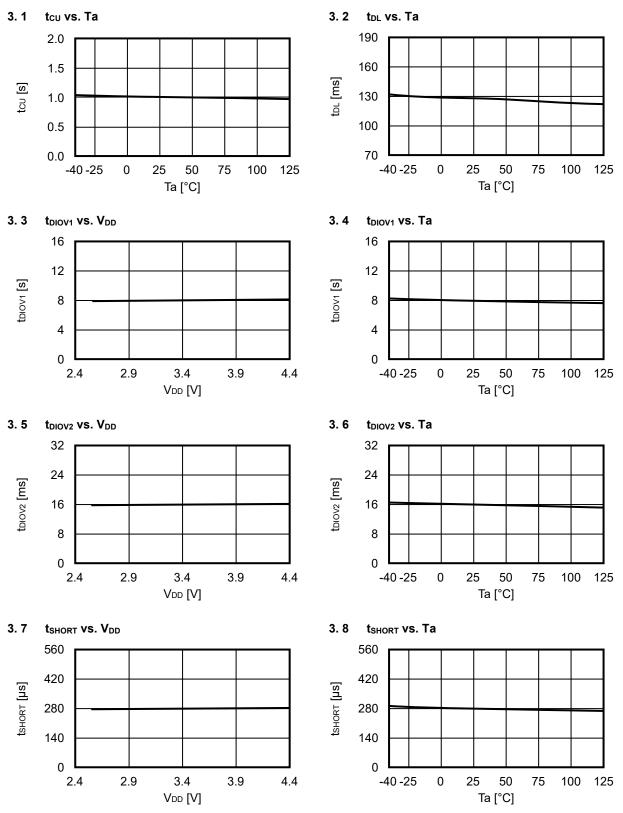
VDD [V]

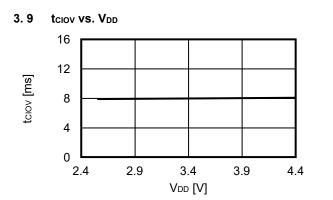
Ta [°C]

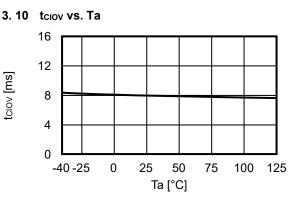


AUTOMOTIVE, 125°C OPERATION, BATTERY PROTECTION IC FOR 1-CELL PACK Rev.1.1_00 S-19161A Series

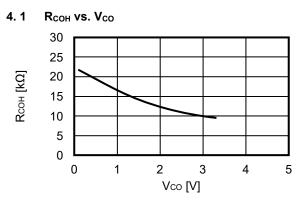
3. Delay time

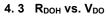


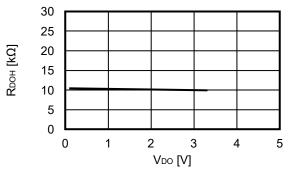




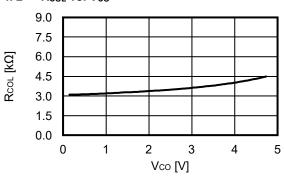
4. Output resistance



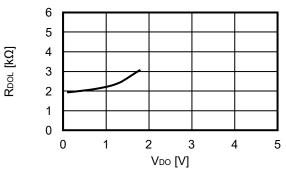




4. 2 R_{COL} vs. V_{CO}

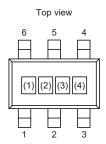






Marking Specifications

1. SOT-23-6



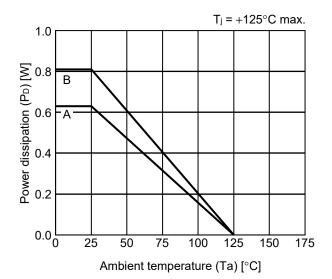
(1) to (3): (4): Product code (Refer to **Product name vs. Product code**) Lot number

Product name vs. Product code

Dreduct Name	Product Code				
Product Name	(1)	(2)	(3)		
S-19161AACA-M6T1U7	b	Ν	D		

Power Dissipation

SOT-23-6



Board	Power Dissipation (P _D)
А	0.63 W
В	0.81 W
С	-
D	-
E	-

SOT-23-3/3S/5/6 Test Board

) IC Mount Area

(1) Board A



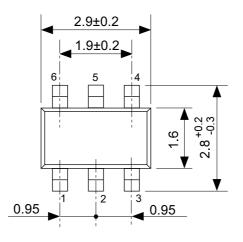
Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		2		
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070		
	2	-		
	3	-		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

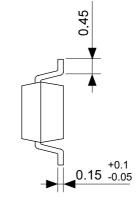
(2) Board B

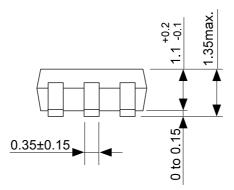


Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		4		
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070		
	2	74.2 x 74.2 x t0.035		
	3	74.2 x 74.2 x t0.035		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

No. SOT23x-A-Board-SD-2.0

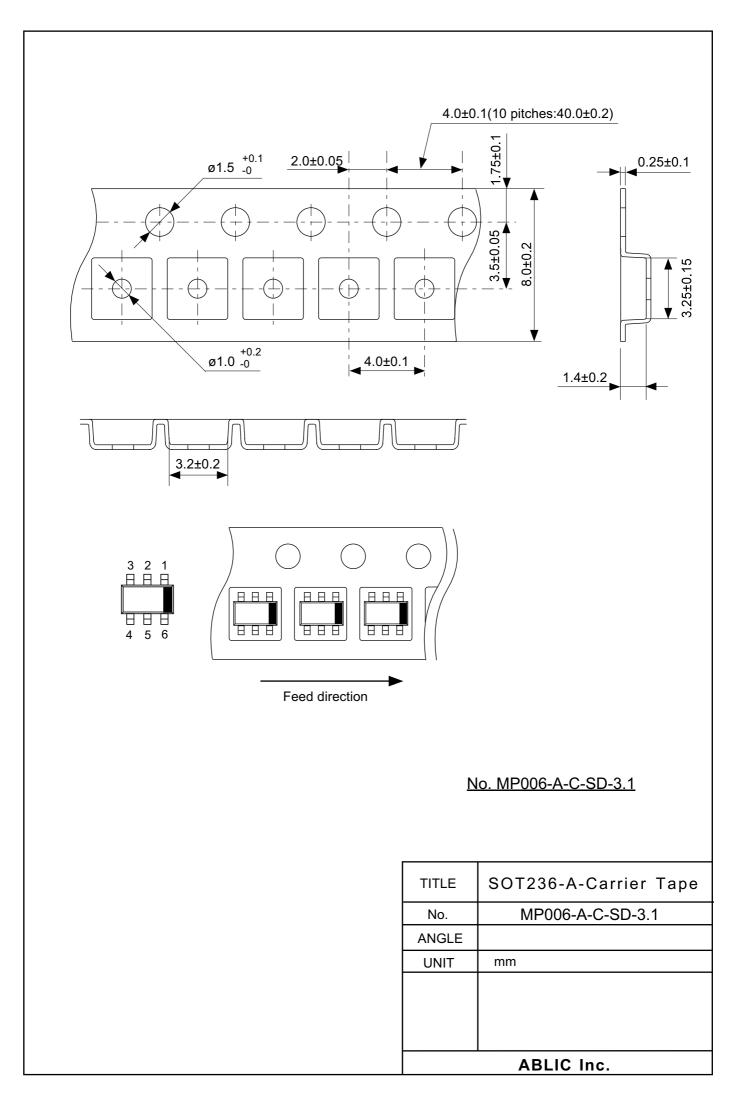


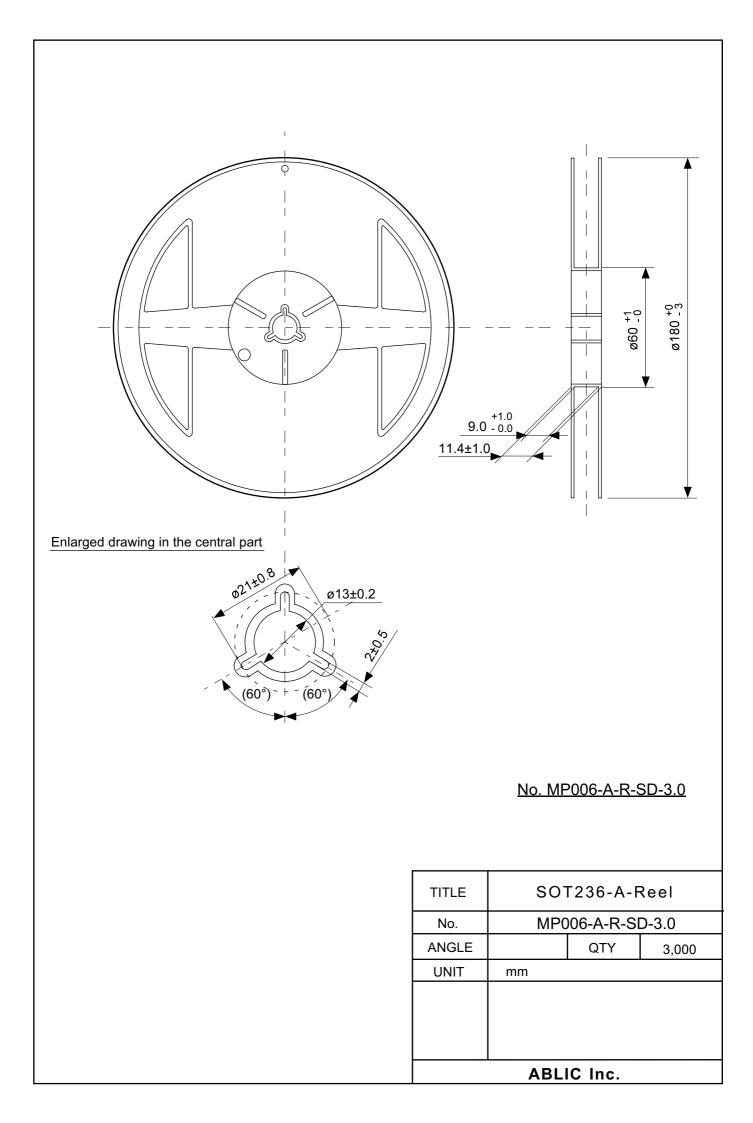




No. MP006-A-P-SD-2.1

TITLE	SOT236-A-PKG Dimensions			
No.	MP006-A-P-SD-2.1			
ANGLE	$\bigoplus \in \exists$			
UNIT	mm			
	ABLIC Inc.			





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2.4-2019.07

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